Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
LI	4376	((memory cell) near (region\$1 area\$1 part\$1 portion\$1)) with (peripher\$2 near (region\$1 area\$1 part\$1 portion\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/08/01 16:01
L2	3	1 and (remov\$3 near2 (hard near mask) near2 (spacer\$1 sidewall\$1 (side near wall\$1)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/08/01 15:54
L3	21	1 and (remov\$3 with (hard near mask) with (spacer\$1 sidewall\$1 (side near wall\$1)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/08/01 16:00
L4	0	((memory cell) near (region\$1 area\$1 part\$1 portion\$1)) AND (peripher\$2 near (region\$1 area\$1 part\$1 portion\$1)) AND remov\$3 AND (hard near mask) AND (spacer\$1 sidewall\$1 (side near wall\$1)) AND (conduct\$3 near spacer\$1) AND (spac\$3 near distance) AND (line near pattern\$1) AND width AND (insulat\$3 near (layer film)) AND (photoresist (photo near resist)) AND (depp near contact\$1) AND (etch\$1 near mask).CLM.	US-PGPUB; USPAT	OR	ON	2005/08/01 15:59
L5	642	(remov\$3 with (hard near mask) with (spacer\$1 sidewall\$1 (side near wall\$1)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR .	ON	2005/08/01 16:00
L6	429	5 and ((line near pattern\$1) BL (bit neas line\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/08/01 16:01
L7	170	5 and ((line near pattern\$1) BL (bit near line\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/08/01 16:02
L8	5021	((memory cell) near (region\$1 area\$1 part\$1 portion\$1)) same (peripher\$2 near (region\$1 area\$1 part\$1 portion\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/08/01 16:02

L9	14	8 and 7	US-PGPUB;	OR	ON	2005/08/01 16:02
1			USPAT;			
			USOCR;			
			EPO; JPO;			,
			DERWENT			
			; IBM_TDB			